BOURNS®

- 7 A Continuous Collector Current
- 15 A Peak Collector Current
- 60 W at 25°C Case Temperature



Pin 2 is in electrical contact with the mounting base.

absolute maximum ratings at 25°C case temperature (unless otherwise noted)

RATING	SYMBOL	VALUE	UNIT		
Collector base veltage $(I - 0)$	BU406	V	400	v	
Collector-base voltage (IE = 0)	BU407	V CBO	330		
		V	400	V	
Conector-ennitier voltage ($v_{BE} = -2 v$)	BU407	VCEX	330	v	
Collector emitter voltage $(L = 0)$	BU406	V	200	V	
$Collector-entitler voltage (I_B = 0)$	BU407	V CEO	150		
Emitter-base voltage	V _{EB}	6	V		
Continuous collector current	Ι _C	7	A		
Peak collector current (see Note 1)	I _{CM}	15	A		
Continuous base current	Ι _Β	4	A		
Continuous device dissipation at (or below) 25°C case temperature	P _{tot}	60	W		
Operating junction temperature range	Т _ј	-55 to +150	°C		
Storage temperature range	T _{stg}	-55 to +150	°C		

NOTE 1: This value applies for $t_p \leq 10$ ms, duty cycle $\leq 2\%.$

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electrical characteristics at 25°C case temperature (unless otherwise noted)

PARAMETER TEST CONDITIONS			MIN	ТҮР	MAX	UNIT				
V _{(BR)CEO}	Collector-emitter breakdown voltage	I _C =	30 mA	$I_{B} = 0$			140			V
I _{CES}	Collector-emitter cut-off current	V _{CE} =	400 V 330 V	$V_{BE} = 0$ $V_{BE} = 0$		BU406 BU407			5 5	
		V _{CE} =	250 V	$V_{BE} = 0$		BU406			0.1	mA
		V _{CE} = V _{CE} =	200 V 250 V	V _{BE} = 0 V _{BE} = 0	T _C = 150°C	BU407 BU406			0.1 1	
		V _{CE} =	200 V	$V_{BE} = 0$	$T_{\rm C} = 150^{\circ}{\rm C}$	BU407			1	
I _{EBO}	Emitter cut-off current	V _{EB} =	6 V	$I_{\rm C} = 0$					1	mA
h _{FE}	Forward current transfer ratio	V _{CE} =	10 V 10 V	$I_{\rm C} = 4 \rm A$ $I_{\rm C} = 0.5 \rm A$	(see Notes 2 ar	nd 3)	12 20			
V _{CE(sat)}	Collector-emitter saturation voltage	I _B =	0.5 A	$I_{\rm C} = 5$ A	(see Notes 2 ar	nd 3)			1	V
V _{BE(sat)}	Base-emitter saturation voltage	I _B =	0.5 A	I _C = 5 A	(see Notes 2 ar	nd 3)			1.2	V
f _t	Current gain bandwidth product	V _{CE} =	5 V	I _C = 0.5 A	f = 1 MHz	(see Note 4)		6		MHz
C _{ob}	Output capacitance	V _{CB} =	20 V	$I_E = 0$	f = 1 MHz			60		pF

NOTES: 2. These parameters must be measured using pulse techniques, $t_p = 300 \ \mu s$, duty cycle $\leq 2\%$.

3. These parameters must be measured using voltage-sensing contacts, separate from the current carrying contacts.

4. To obtain f_t the $[h_{FE}]$ response is extrapolated at the rate of -6 dB per octave from f = 1 MHz to the frequency at which $[h_{FE}] = 1$.

thermal characteristics

PARAMETER			ТҮР	MAX	UNIT
$R_{\theta JC}$	Junction to case thermal resistance			2.08	°C/W
$R_{\theta JA}$	Junction to free air thermal resistance			70	°C/W

inductive-load-switching characteristics at 25°C case temperature (unless otherwise noted)

	PARAMETER	TEST CONDITIONS [†]			MIN	ТҮР	МАХ	UNIT
t _s	Storage time	I _C = 5 A	la	(see Figures 1 and 2)		2.7		μs
t _(off)	Turn off time		¹ B(end) = 0.077				750	ns

[†] Voltage and current values shown are nominal; exact values vary slightly with transistor parameters.

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PARAMETER MEASUREMENT INFORMATION





Figure 2. Inductive-Load Switching Waveforms

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AUGUST 1978 - REVISED SEPTEMBER 2002 Specifications are subject to change without notice.



TYPICAL CHARACTERISTICS



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MAXIMUM SAFE OPERATING REGIONS



Figure 6.

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MECHANICAL DATA

TO-220

3-pin plastic flange-mount package

This single-in-line package consists of a circuit mounted on a lead frame and encapsulated within a plastic compound. The compound will withstand soldering temperature with no deformation, and circuit performance characteristics will remain stable when operated in high humidity conditions. Leads require no additional cleaning or processing when used in soldered assembly.



B. Mounting tab corner profile according to package version.

C. Typical fixing hole centre stand off height according to package version. Version 1, 18.0 mm. Version 2, 17.6 mm.